

Publisher Correction: Tunnelling spectroscopy of gate-induced superconductivity in MoS₂

Davide Costanzo, Haijing Zhang, Bojja Aditya Reddy, Helmuth Berger and Alberto F. Morpurgo 

Correction to: *Nature Nanotechnology* <https://doi.org/10.1038/s41565-018-0122-2>, published online 30 April 2018.

In the version of this Article originally published, an error during typesetting led to the curve in Fig. 2a being shifted to the right, and the curves in the inset of Fig. 2a being displaced. The figure has now been corrected in all versions of the Article; the original and corrected Fig. 2a are shown below.

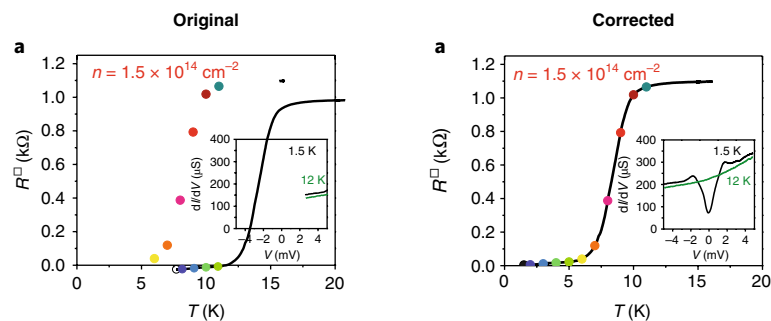


Fig. 2a | Original and corrected.

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<https://doi.org/10.1038/s41565-018-0159-2>

Publisher Correction: Quantum engineering of transistors based on 2D materials heterostructures

Giuseppe Iannaccone, Francesco Bonaccorso, Luigi Colombo and Gianluca Fiori

Correction to: *Nature Nanotechnology* <https://doi.org/10.1038/s41565-018-0082-6>, published online 6 March 2018.

In the version of this Perspective originally published, in the email address for the author Giuseppe Iannaccone, the surname was incorrectly given as “innaconne”; this has now been corrected in all versions of the Perspective. Also, an error in the production process led to Figs. 1, 2 and 3 being of low resolution; these have now been replaced with higher-quality versions.

Published online: 22 May 2018

<https://doi.org/10.1038/s41565-018-0136-9>

Publisher Correction: 2D MoS₂ as an efficient protective layer for lithium metal anodes in high-performance Li-S batteries

Eunho Cha, Mumukshu D. Patel, Juhong Park, Jeongwoon Hwang, Vish Prasad, Kyeongjae Cho and Wonbong Choi

Correction to: *Nature Nanotechnology* <https://doi.org/10.1038/s41565-018-0061-y>, published online 12 February 2018.

In the version of this Article originally published, a technical error in typesetting led to the traces in Fig. 3a being trimmed and made to overlap. The figure has now been corrected with the traces as supplied by the authors; the original and corrected Fig. 3a are shown below. Also, in the last paragraph of the section “Mechanistic study on Li diffusion in MoS₂” the authors incorrectly included the term ‘high-concentration’ in the text “the Li diffusion will be dominated by high-concentration Li migration on the surface of T-MoS₂ with a much smaller energy barrier (0.155 eV) to overcome”. This term has now been removed from all versions of the Article. Finally, the authors have added an extra figure in the Supplementary Information (Supplementary Fig. 19) to show galvanostatic tests at 1 and 3 mA cm⁻² for the MoS₂-coated Li symmetric cells. The caption to Fig. 3 of the Article has been amended to reflect this, with the added wording “Galvanostatic tests at 1 and 3 mA cm⁻² can be found in Supplementary Fig. 19.”

Supplementary information is available for this correction at <https://doi.org/10.1038/s41565-018-0061-y>

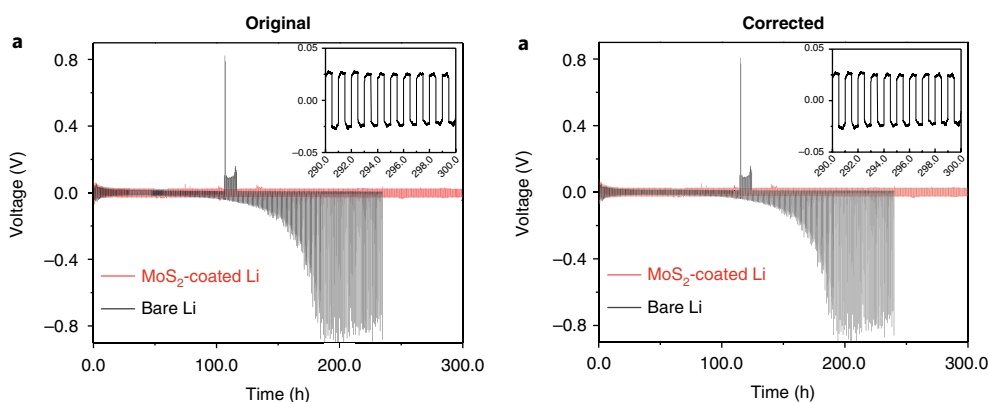


Fig. 3a | Original and corrected. The corrected version includes traces as supplied by the authors.

Published online: 4 April 2018

<https://doi.org/10.1038/s41565-018-0095-1>